



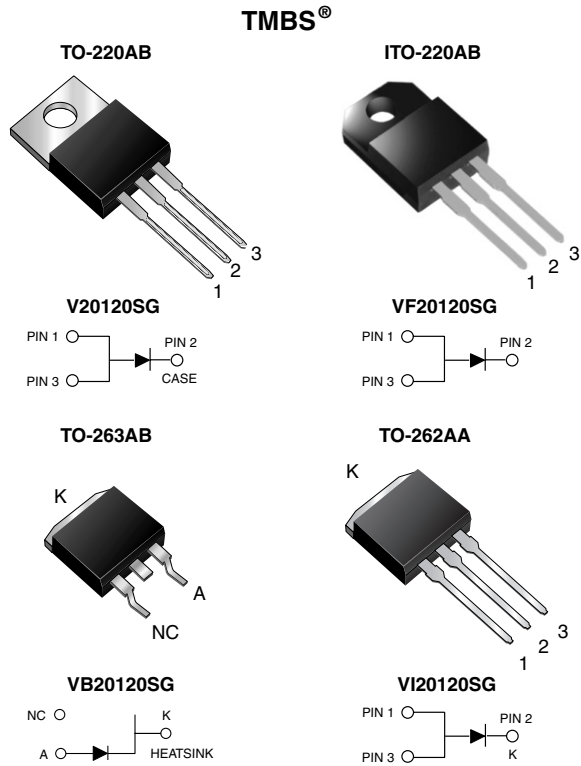
New Product

# V20120SG, VF20120SG, VB20120SG & VI20120SG

Vishay General Semiconductor

## High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.54 \text{ V}$  at  $I_F = 5 \text{ A}$



### FEATURES



- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020C, LF max peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 seconds (for TO-220AB, ITO-220AB & TO-262AA package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, free-wheeling diodes, oring diode, dc-to-dc converters and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB & TO-262AA

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	20 A
$V_{RRM}$	120 V
$I_{FSM}$	150 A
$V_F$ at $I_F = 20 \text{ A}$	0.78 V
$T_J \text{ max.}$	150 °C

### MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V20120SG	VF20120SG	VB20120SG	VI20120SG	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$		120			V
Maximum average forward rectified current (see Fig. 1)	$I_{F(AV)}$		20			A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$		150			A
Isolation voltage (ITO-220AB only) From terminal to heatsink $t = 1 \text{ minute}$	$V_{AC}$		1500			V
Operating junction and storage temperature range	$T_J, T_{STG}$		- 40 to + 150			°C

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	at I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>(BR)</sub>	120 (minimum)	-	V
Instantaneous forward voltage <sup>(1)</sup>	at I <sub>F</sub> = 5 A I <sub>F</sub> = 10 A I <sub>F</sub> = 20 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.62 0.81 1.20	- - 1.33	
	at I <sub>F</sub> = 5 A I <sub>F</sub> = 10 A I <sub>F</sub> = 20 A	T <sub>A</sub> = 125 °C		0.54 0.65 0.78	- - 0.88	
Reverse current <sup>(2)</sup>	at V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	10 7	- -	
	at V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C		- 12	250 25	μA mA

**Notes:**

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: 10 ms pulse width

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	V20120SG	VF20120SG	VB20120SG	VI20120SG	UNIT
Typical thermal resistance	R <sub>θJC</sub>	2.2	4.2	2.2	2.2	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V20120SG-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VF20120SG-E3/4W	1.75	4W	50/tube	Tube
TO-263AB	VB20120SG-E3/4W	1.38	4W	50/tube	Tube
TO-263AB	VB20120SG-E3/8W	1.38	8W	800/reel	Tape and reel
TO-262AA	VI20120SG-E3/4W	1.45	4W	50/tube	Tube

**RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

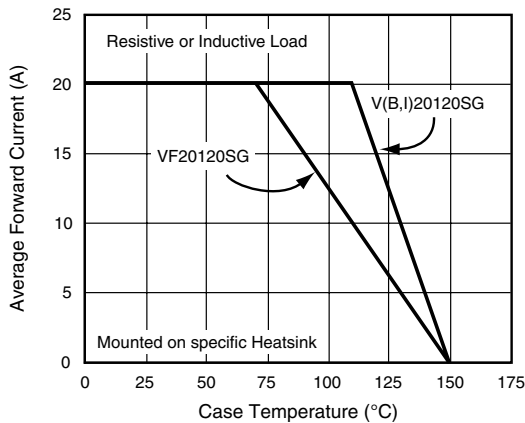


Figure 1. Forward Current Derating Curve

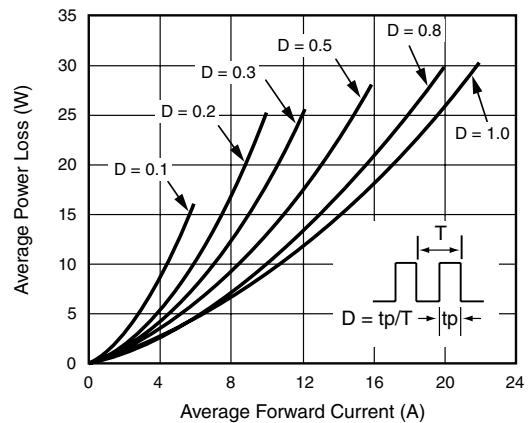


Figure 2. Forward Power Loss Characteristics



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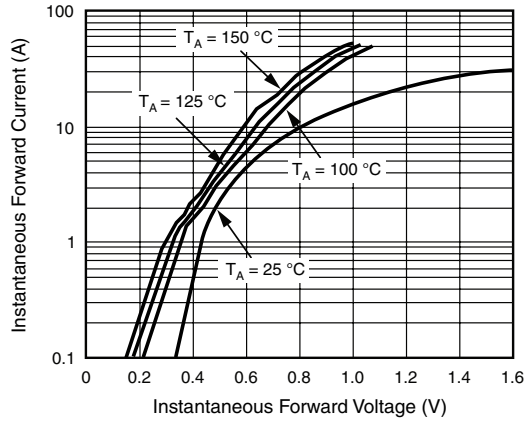


Figure 3. Typical Instantaneous Forward Characteristics

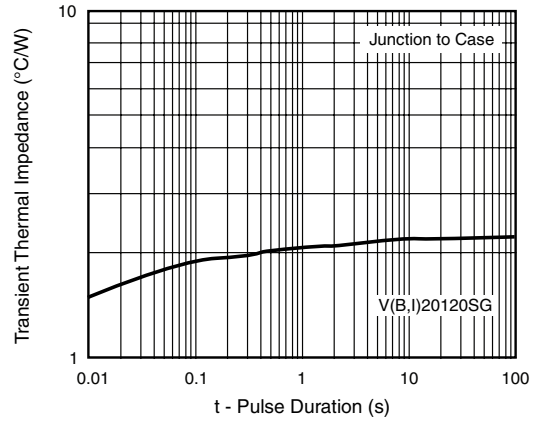


Figure 6. Typical Transient Thermal Impedance

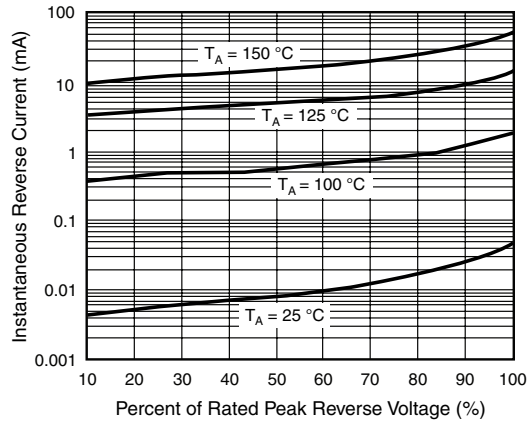


Figure 4. Typical Reverse Characteristics

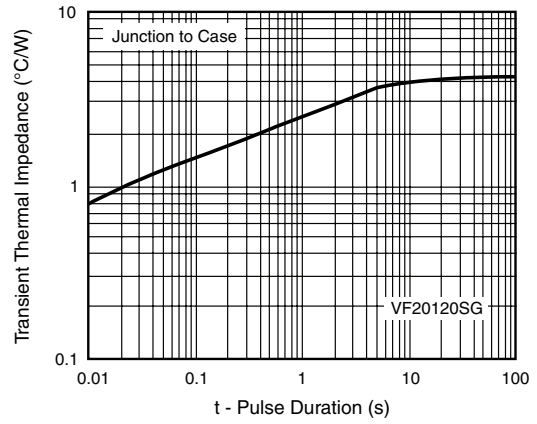


Figure 7. Typical Transient Thermal Impedance

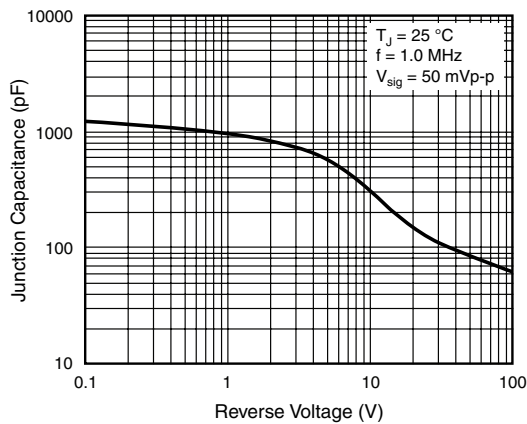
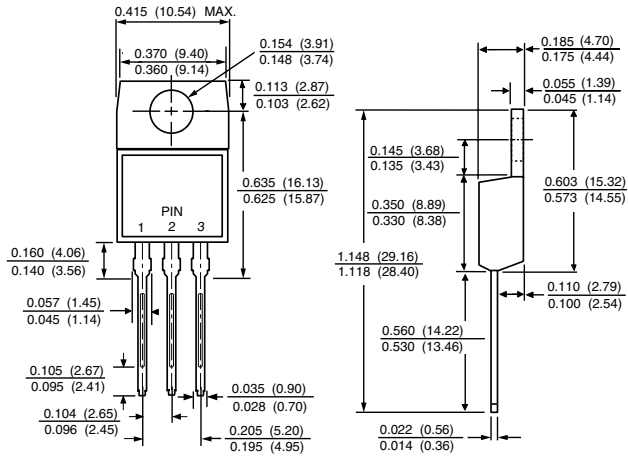


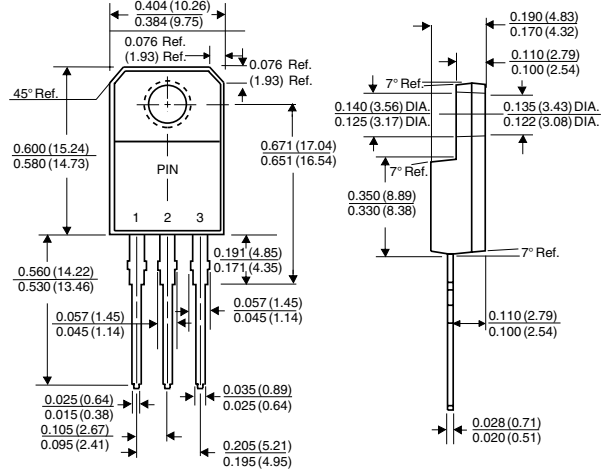
Figure 5. Typical Junction Capacitance

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

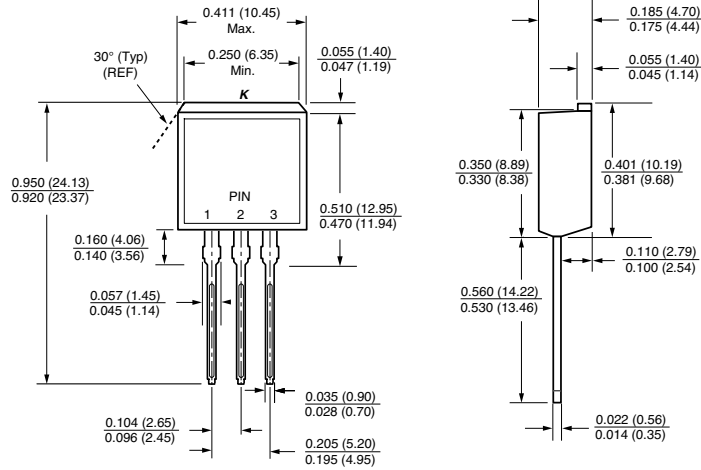
TO-220AB



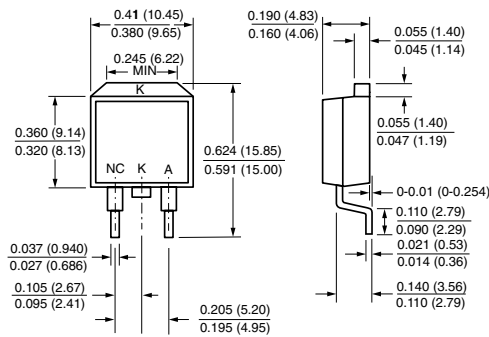
ITO-220AB



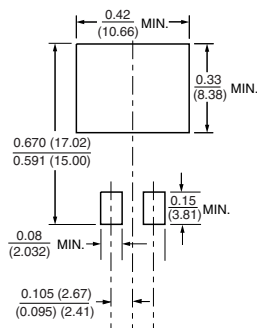
TO-262AA



TO-263AB



Mounting Pad Layout





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